

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- Surface-mounted package
 Super Trench
 Tj max 175°C
- Advanced trench cell design
 MSL1

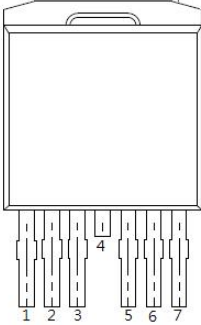
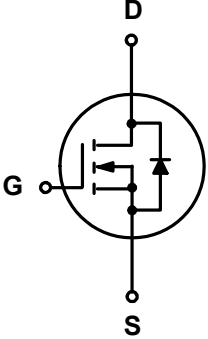
1.2 Applications

- Power Tool appliances
 BMS appliances
- High power inverter system
 Inverter appliances

1.3 Quick reference

- BV ≧ 100 V
 P_{tot} ≧ 227 W
 I_D ≧ 300 A
- R_{DS(ON)} ≧ 1.3mΩ @ V_{GS} = 10 V
 R_{DS(ON)} ≧ 1.9mΩ @ V_{GS} = 4.5 V

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO-263-7L(D2PAK)	
2,3	Source (S)		
4	Drain(D)		
5,6,7	Source (S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _C = 25 °C	100	-	V
V _{GS}	Gate-Source Voltage	T _C = 25 °C	-	±20	V
I _D ^{***}	Drain Current (DC)	T _C = 25 °C, V _{GS} = 10 V	-	300	A
		T _C = 100 °C, V _{GS} = 10 V	-	186	A
I _{DM} ^{*,***}	Drain Current (Pulsed)	T _C = 25 °C, V _{GS} = 10 V	-	1200	A
P _{tot}	Drain power dissipation	T _C = 25 °C	-	227	W
T _{stg}	Storage Temperature		-55	175	°C
T _J	Junction Temperature		-	175	°C
I _S	Continuous-Source Current	T _C = 25 °C	-	300	A
E _{AS}	Single Pulsed Avalanche Energy	VDD=100V , L=0.1mH	-	605	mJ
R _{θJA} ^{**}	Thermal Resistance- Junction to Ambient		-	40	°C/W
R _{θJC} ^{**}	Thermal Resistance- Junction to Case		-	0.55	

Notes :

- * Pulse width ≤ 300 μs, duty cycle ≤ 2 %
- ** Surface Mounted on minimum footprint pad area.
- *** Limited by bonding wire

4. Marking Information

Product Name	Marking
KJ0110DM7	<div style="background-color: black; color: white; padding: 5px; text-align: center;"> KJ0110DM7 AYWW01 XXXXXX </div>

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ0110DM7	TO263-7(D2-PAK)			800	

Note: KUAIJIXIN defines “ Green ” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics ($T_A=25^\circ$ Unless Otherwise Noted)

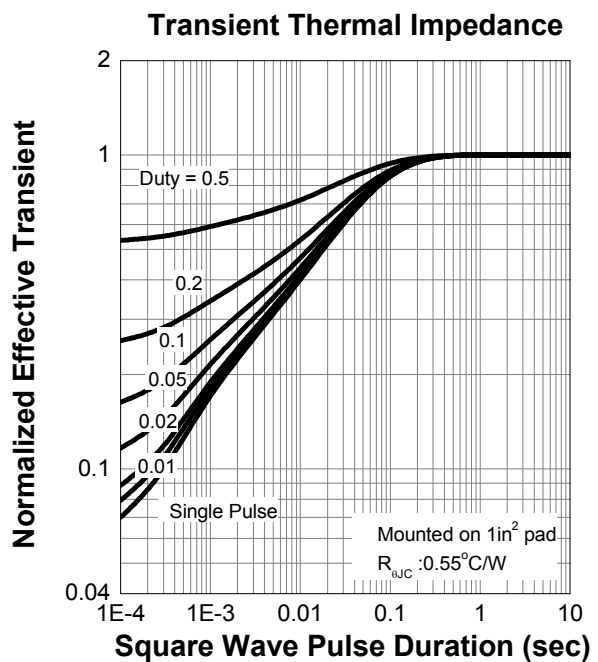
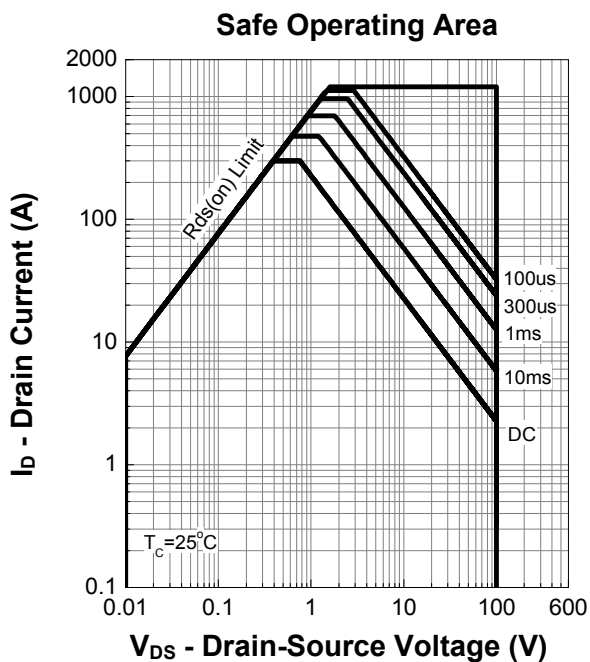
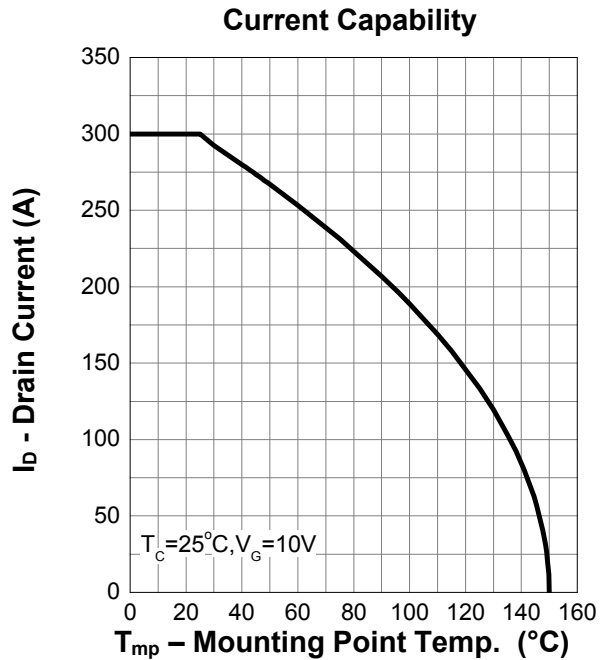
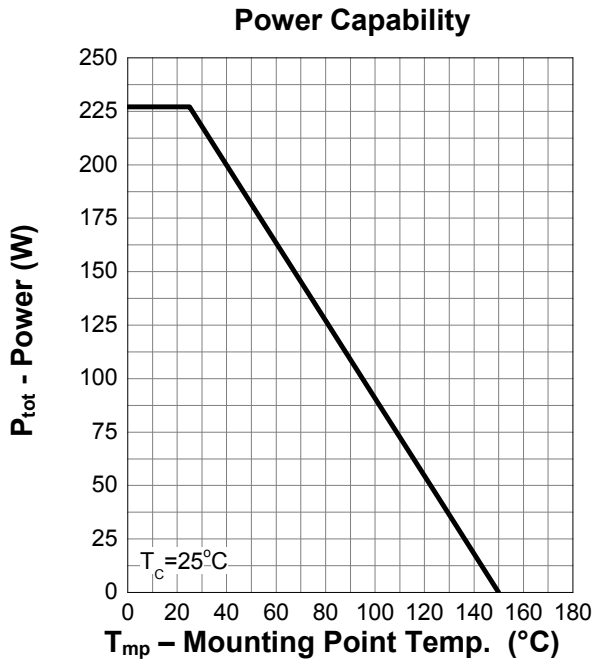
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = 250\ \mu\text{A}$	100	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\ \mu\text{A}$	1	-	3	V
I_{DSS}	Drain Leakage Current	$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}$	-	-	1	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
$R_{DS(ON)}^a$	On-State Resistance	$V_{GS} = 10\text{ V}, I_{DS} = 50\text{ A}$	-	1.1	1.3	m Ω
		$V_{GS} = 4.5\text{ V}, I_{DS} = 25\text{ A}$	-	1.5	1.9	
Diode Characteristics						
V_{SD}^a	Diode Forward Voltage	$I_{SD} = 50\text{ A}, V_{GS} = 0\text{ V}$	-	-	1.3	V
t_{rr}	Reverse Recovery Time	$I_{DS} = 50\text{ A}, V_{GS} = 0\text{ V}$ $dI_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	137	-	nS
Q_{rr}	Reverse Recovery Charge		-	347	-	nC
Dynamic Characteristics^b						
C_{iss}	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 50\text{ V}$ Frequency = 1 MHz	-	11876	-	pF
C_{oss}	Output Capacitance		-	2041	-	
C_{rss}	Reverse Transfer Capacitance		-	106	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = 50\text{ V}, V_{GEN} = 10\text{ V},$ $R_G = 4.5\ \Omega, R_L = 2.5\ \Omega,$ $I_{DS} = 50\text{ A}$	-	29	-	nS
t_r	Turn-on Rise Time		-	121	-	
$t_d(off)$	Turn-off Delay Time		-	198	-	
t_f	Turn-off Fall Time		-	175	-	
Gate Charge Characteristics^b						
Q_g	Total Gate Charge	$V_{DS} = 50\text{ V}, V_{GS} = 10\text{ V},$ $I_{DS} = 50\text{ A}$	-	244	-	nC
Q_{gs}	Gate-Source Charge		-	46	-	
Q_{gd}	Gate-Drain Charge		-	67	-	

Notes :

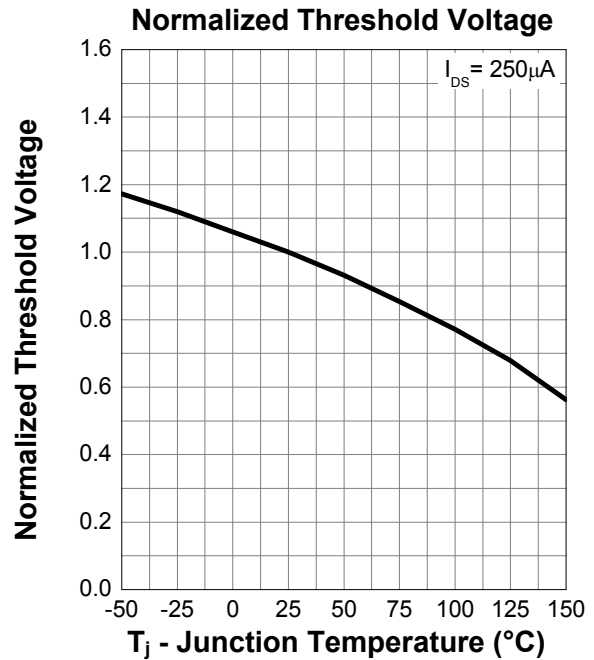
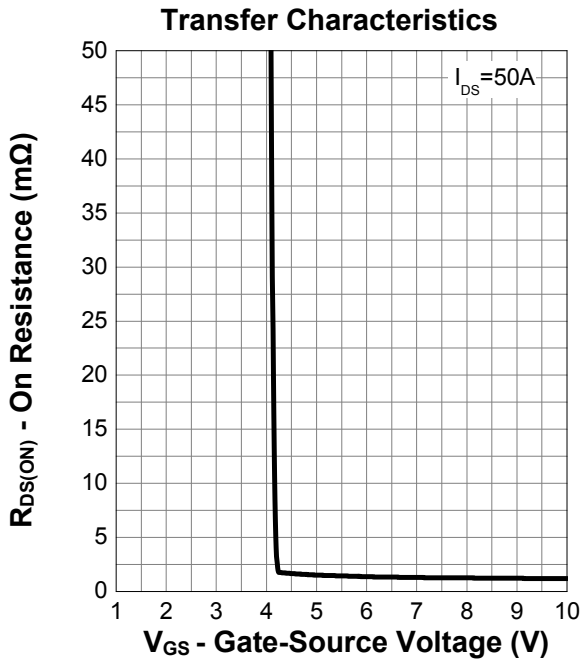
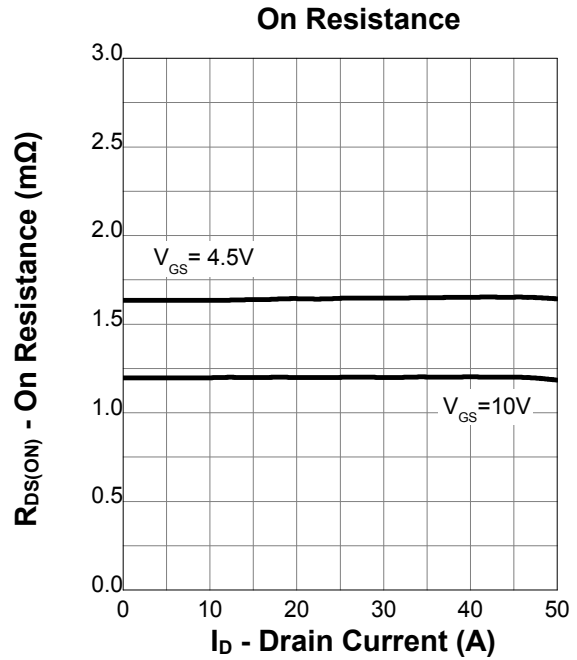
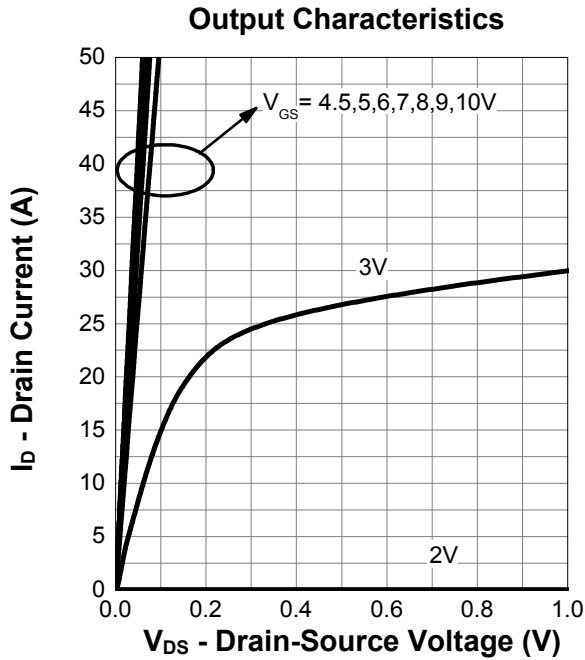
a : Pulse test ; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

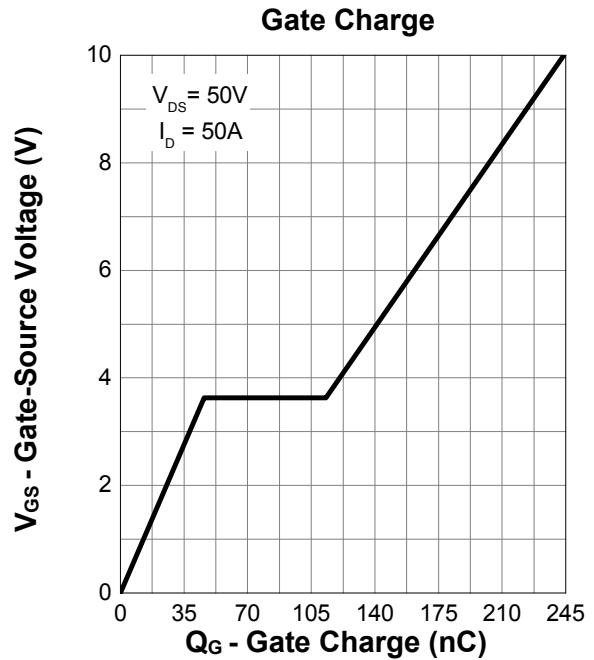
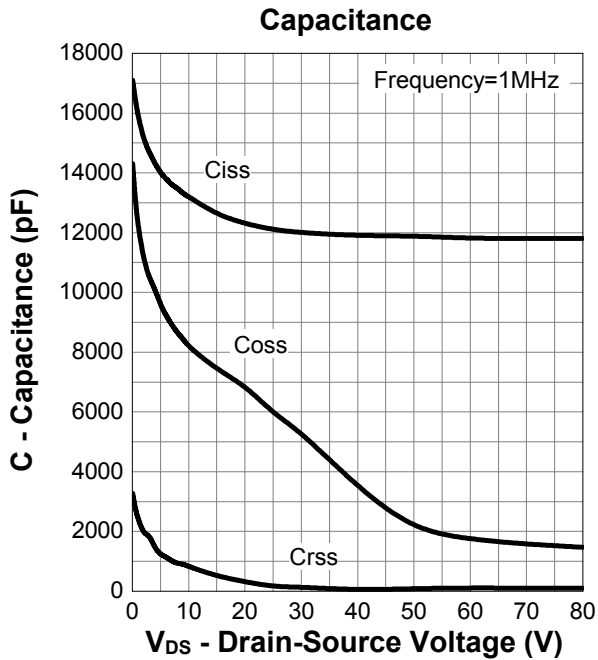
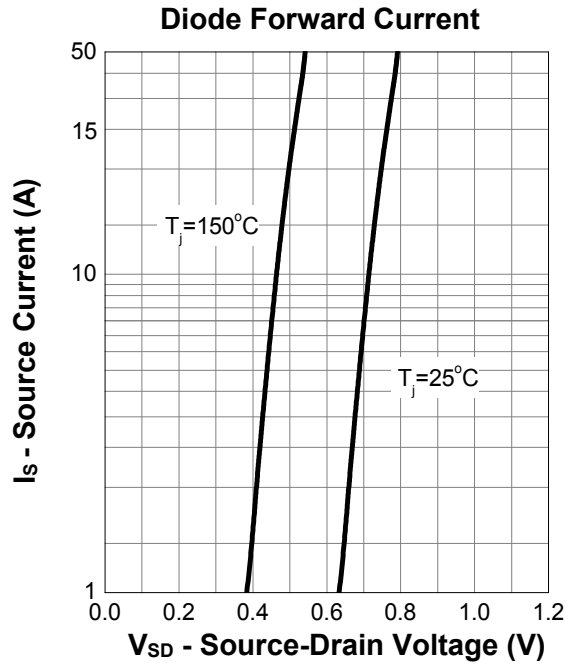
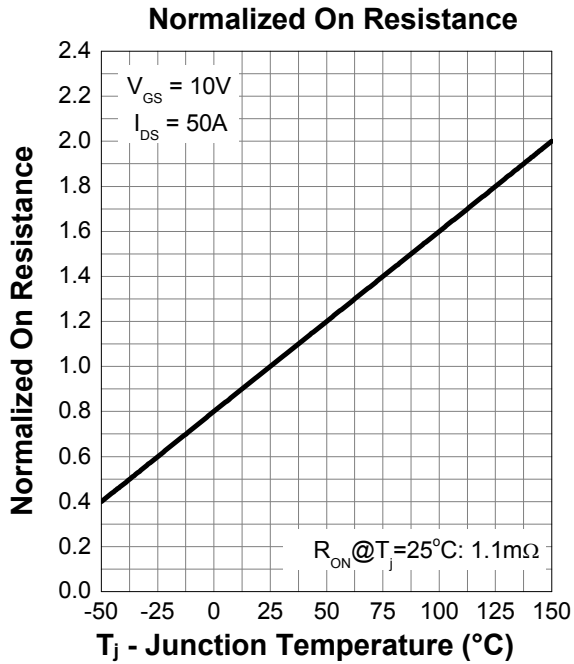
7. Typical Characteristics



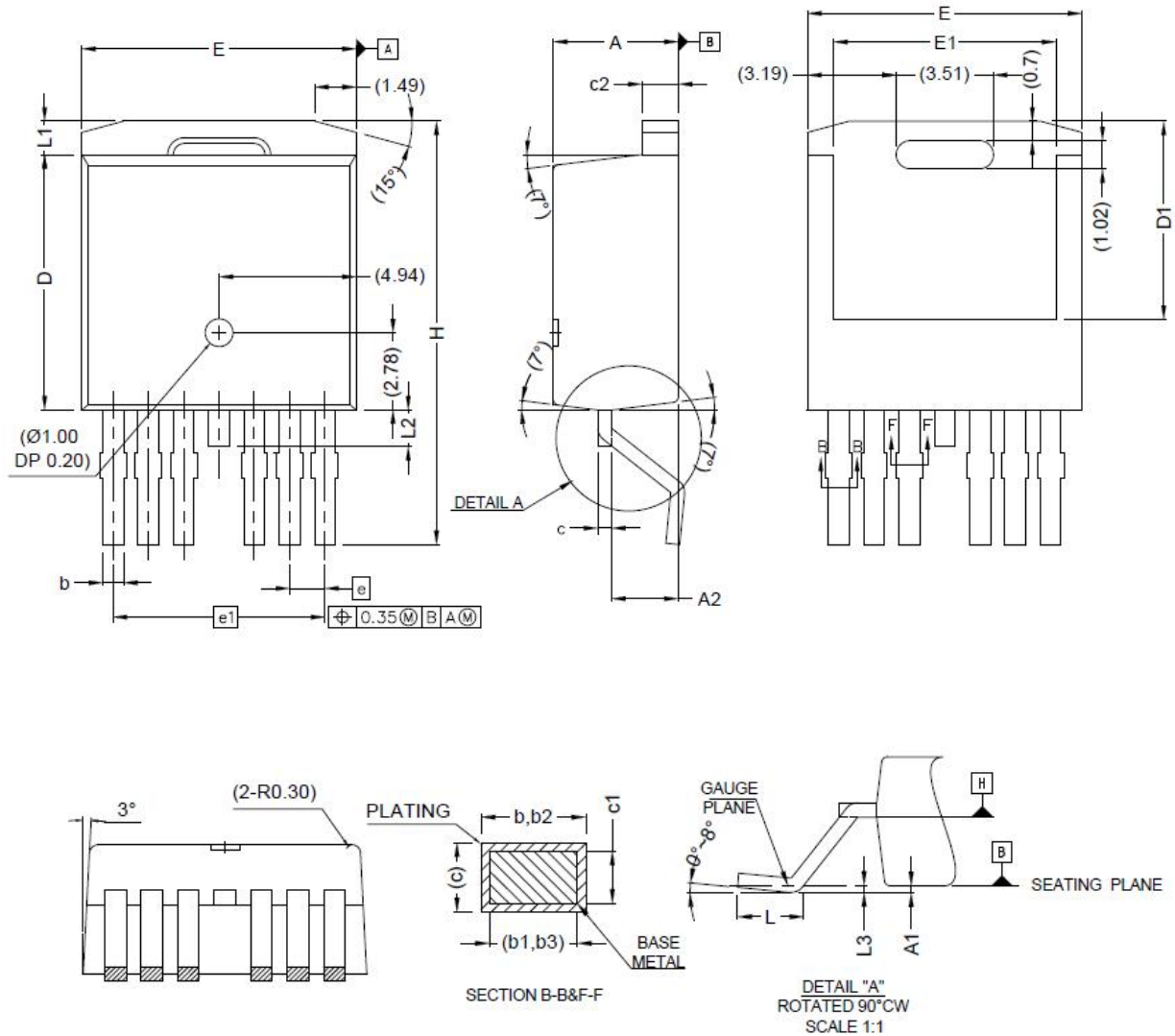
7. Typical Characteristics (cont.)



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8. Package Dimensions TO263-7(D2-PAK)



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TO263-7(D2-PAK)

SYMBOL	MIN	MAX
A	4.30	4.70
A1	-	0.25
A2	2.20	2.60
b	0.65	0.85
b1	0.65	0.80
b2	0.80	1.00
b3	0.80	0.95
c	0.45	0.60
c1	0.45	0.55
c2	1.25	1.40
D	9.00	9.40
D1	6.86	7.42
E	9.68	10.08
E1	7.70	8.30
e	1.27 BSC	
e1	7.62 BSC	
L	1.78	2.79
L1	-	1.60
L2	-	1.78
L3	0.25BSC	
H	14.61	15.88